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## 2.5-V PHASE-LOCKED-LOOP CLOCK DRIVER

## **FEATURES**

- Spread-Spectrum Clock Compatible
- Operating Frequency: 60 MHz to 220 MHz
- Low Jitter (Cycle-Cycle): ±60 ps (±40 ps at 200 MHz)
- Low Static Phase Offset: ±50 ps
- Low Jitter (Period): ±60 ps (±30 ps at 200 MHz)
- 1-to-4 Differential Clock Distribution (SSTL2)
- Best in Class for V<sub>OX</sub> = V<sub>DD</sub>/2 ±0.1 V
- Operates From Dual 2.6-V or 2.5-V Supplies
- Available in a 28-Pin TSSOP Package
- Consumes < 100-μA Quiescent Current</li>
- External Feedback Pins (FBIN, FBIN) Are Used to Synchronize the Outputs to the Input Clocks
- Meets/Exceeds JEDEC Standard (JESD82-1)
   For DDRI-200/266/333 Specification
- Meets/Exceeds Proposed DDRI-400 Specification (JESD82-1A)
- Enters Low-Power Mode When No CLK Input Signal Is Applied or PWRDWN Is Low

## **APPLICATIONS**

- DDR Memory Modules (DDR400/333/266/200)
- Zero-Delay Fan-Out Buffer

#### DESCRIPTION

The CDCVF855 is a high-performance, low-skew, low-jitter, zero-delay buffer that distributes a differential clock input pair (CLK, CLK) to 4 differential pairs of clock outputs (Y[0:3], Y[0:3]) and one differential pair of feedback clock outputs (FBOUT, FBOUT). The clock outputs are controlled by the clock inputs (CLK, CLK), the feedback clocks (FBIN,  $\overline{\text{FBIN}}$ ), and the analog power input (AV<sub>DD</sub>). When PWRDWN is high, the outputs switch in phase and frequency with CLK. When PWRDWN is low, all outputs are disabled to a high-impedance state (3-state) and the PLL is shut down (low-power mode). The device also enters this low-power mode when the input frequency falls below a suggested detection frequency that is below 20 MHz (typical 10 MHz). An input frequency-detection circuit detects the low-frequency condition and, after applying a >20-MHz input signal, this detection circuit turns the PLL on and enables the outputs.

When  $AV_{DD}$  is strapped low, the PLL is turned off and bypassed for test purposes. The CDCVF855 is also able to track spread-spectrum clocking for reduced EMI.

Because the CDCVF855 is based on PLL circuitry, it requires a stabilization time to achieve phase-lock of the PLL. This stabilization time is required following power up. The CDCVF855 is characterized for both commercial and industrial temperature ranges.

#### **AVAILABLE OPTIONS**

T <sub>A</sub>	TSSOP (PW)			
−40°C to 85°C	CDCVF855PW			



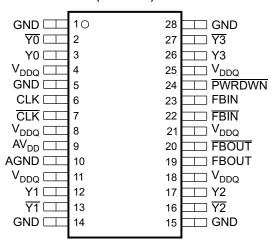
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



# FUNCTION TABLE (Select Functions)

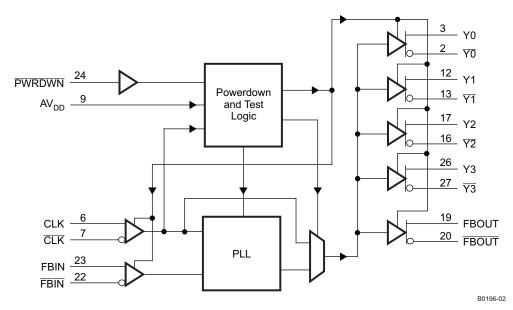
	INP	UTS		OUTPUTS				PLL
AVDD	PWRDWN	CLK	CLK	Y[0:3]	<u>Y[0:3]</u>	FBOUT	FBOUT	
GND	Н	L	Н	L	Н	L	Н	Bypassed/off
GND	Н	Н	L	Н	L	Н	L	Bypassed/off
Х	L	L	Н	Z	Z	Z	Z	Off
X	L	Н	L	Z	Z	Z	Z	Off
2.5 V (nom)	Н	L	Н	L	Н	L	Н	On
2.5 V (nom)	Н	Н	L	Н	L	Н	L	On
2.5 V (nom)	Х	<20 MHz	<20 MHz	Z	Z	Z	Z	Off

# PW PACKAGE (TOP VIEW)



P0043-02

## **FUNCTIONAL BLOCK DIAGRAM**





#### Table 2. TERMINAL FUNCTIONS

TE	TERMINAL		DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
AGND	10	_	Ground for 2.5-V analog supply
$AV_{DD}$	9	_	2.5-V analog supply
CLK, CLK	6, 7	I	Differential clock input
FBIN, FBIN	22, 23	I	Feedback differential clock input
FBOUT, FBOUT	19, 20	0	Feedback differential clock output
GND	1, 5, 14, 15, 28	_	Ground
PWRDWN	24	I	Output enable for Y and $\overline{Y}$
$V_{DDQ}$	4, 8, 11, 18, 21, 25	-	2.5-V supply
<del>Y0</del> , Y0	2, 3	0	Buffered output copies of input clock, CLK, CLK
Y1, <del>Y</del> 1	12, 13	0	Buffered output copies of input clock, CLK, CLK
<del>Y2</del> , Y2	16, 17	0	Buffered output copies of input clock, CLK, CLK
Y3, <del>Y</del> 3	26, 27	0	Buffered output copies of input clock, CLK, CLK

## **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range (unless otherwise noted) (1)

$V_{DDQ}$ , $AV_{DD}$	Supply voltage range		0.5 V to 3.6 V
VI	Input voltage range <sup>(2)(3)</sup>		-0.5 V to V <sub>DDQ</sub> + 0.5 V
Vo	Output voltage range (2)(3)		-0.5 V to V <sub>DDQ</sub> + 0.5 V
I <sub>IK</sub>	Input clamp current	$V_I < 0 \text{ or } V_I > V_{DDQ}$	±50 mA
I <sub>OK</sub>	Output clamp current	$V_O < 0$ or $V_O > V_{DDQ}$	±50 mA
Io	Continuous output current	$V_O = 0$ to $V_{DDQ}$	±50 mA
I <sub>DDS</sub>	Continuous current to GND or V <sub>DDQ</sub>		±100 mA
T <sub>stg</sub>	Storage temperature range		−65°C to 150°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## THERMAL CHARACTERISTICS

R <sub>θJA</sub> for TSSOP Package <sup>(1)</sup>					
Airflow	High K				
0 ft/min (0 m/min)	94.4°C/W				
150 ft/min (45.72 m/min)	82.8°C/W				

<sup>(1)</sup> The package thermal impedance is calculated in accordance with JESD 51.

<sup>(2)</sup> The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

<sup>(3)</sup> This value is limited to 3.6 V maximum.



## RECOMMENDED OPERATING CONDITIONS

					MIN	NOM MAX	UNIT
	Cumply voltage	$V_{DDQ}$	PC1600 - F	PC3200	2.3	2.7	V
	Supply voltage	AVDE	)		V <sub>DDQ</sub> - 0.12	2.7	V
\/	Low lovel input voltage	CLK,	CLK, FBIN, F	BIN		$V_{DDQ}/2 - 0.18$	<b>\</b>
$V_{IL}$	Low-level input voltage	PWRI	OWN		-0.3	0.7	V
\/	Lligh level input veltage	CLK,	CLK, FBIN, F	BIN	$V_{DDQ}/2 + 0.18$		<b>\</b>
V <sub>IH</sub>	High-level input voltage	PWRI	DWN		1.7	$V_{DDQ} + 0.3$	- V
	DC input signal voltage <sup>(1)</sup>				-0.3	$V_{DDQ} + 0.3$	V
		DC	CLK, FBIN	$V_{DDQ} = 2.3 \text{ V} - 2.7 \text{V}$	0.36	$V_{DDQ} + 0.6$	V
.,	Differential input signal valtage (2)			$V_{DDQ} = 2.425 \text{ V} - 2.7 \text{ V}$	0.25	$V_{DDQ} + 0.6$	
$V_{ID}$	Differential input signal voltage (2)	40	CLIK EDIN	$V_{DDQ} = 2.3 \text{ V} - 2.7 \text{ V}$	0.7	$V_{DDQ} + 0.6$	V
		AC	CLK, FBIN	V <sub>DDQ</sub> = 2.425 V - 2.7 V	0.49	V <sub>DDQ</sub> + 0.6	
V <sub>IX</sub>	Input differential pair cross voltage (3)(4)				V <sub>DDQ</sub> /2 - 0.2	V <sub>DDQ</sub> /2 + 0.2	V
I <sub>OH</sub>	High-level output current					-12	mA
I <sub>OL</sub>	Low-level output current					12	mA
SR	Input slew rate				1	4	V/ns
$T_A$	Operating free-air temperature				-40	85	°C

<sup>(1)</sup> The unused inputs must be held high or low to prevent them from floating.

## **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP (1)	MAX	UNIT
$V_{IK}$	Input voltage, all inputs	$V_{DDQ} = 2.3 \text{ V}, I_{I} = -18 \text{ mA}$			-1.2	V
V	High-level output voltage	$V_{DDQ} = min to max, I_{OH} = -1 mA$	V <sub>DDQ</sub> - 0.1			V
V <sub>OH</sub>	riigii-ievei output voitage	$V_{DDQ} = 2.3 \text{ V}, I_{OH} = -12 \text{ mA}$	1.7			V
V	Low-level output voltage	$V_{DDQ}$ = min to max, $I_{OL}$ = 1 mA			0.1	V
V <sub>OL</sub>	Low-level output voltage	$V_{DDQ} = 2.3 \text{ V}, I_{OL} = 12 \text{ mA}$			0.6	٧
$V_{OD}$	Output voltage swing (2)	Differential outputs are terminated with 120 $\Omega$ .	1.1		$V_{DDQ} - 0.4$	>
V <sub>OX</sub>	Output differential cross-voltage (3)	$C_L = 14 \text{ pF (See Figure 3)}$	V <sub>DDQ</sub> /2 - 0.1	V <sub>DDQ</sub> /2	$V_{DDQ}/2 + 0.1$	٧
I <sub>I</sub>	Input current	$V_{DDQ} = 2.7 \text{ V}, V_{I} = 0 \text{ V to } 2.7 \text{ V}$			±10	μΑ
I <sub>OZ</sub>	High-impedance-state output current	$V_{\rm DDQ}$ = 2.7 V, $V_{\rm O}$ = $V_{\rm DDQ}$ or GND			±10	μΑ
I <sub>DDPD</sub>	Power-down current on V <sub>DDQ</sub> + AV <sub>DD</sub>	CLK and $\overline{\text{CLK}}$ = 0 MHz; $\overline{\text{PWRDWN}}$ = Low; $\Sigma$ of I <sub>DD</sub> and AI <sub>DD</sub>		20	100	μΑ
۸۱	Supply ourrent on AV	f <sub>O</sub> = 170 MHz		6	8	mA
Al <sub>DD</sub>	Supply current on AV <sub>DD</sub>	f <sub>O</sub> = 200 MHz		8	10	IIIA
C <sub>I</sub>	Input capacitance	$V_{DDQ} = 2.5 \text{ V}, V_{I} = V_{DDQ} \text{ or GND}$	2	2.5	3.5	pF

The dc input signal voltage specifies the allowable dc execution of the differential input.

The differential input signal voltage specifies the differential voltage |VTR - VCP| required for switching, where VTR is the true input level and VCP is the complementary input level.

The differential cross-point voltage is expected to track variations of V<sub>CC</sub> and is the voltage at which the differential signals must cross.

 <sup>(1)</sup> All typical values are at a nominal V<sub>DDQ</sub>.
 (2) The differential output signal voltage specifies the differential voltage |VTR - VCP|, where VTR is the true output level and VCP is the complementary output level.

The differential cross-point voltage tracks variations of  $V_{DDQ}$  and is the voltage at which the differential signals must cross.



## **ELECTRICAL CHARACTERISTICS (continued)**

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITION	IS	MIN TYP (1)	MAX	UNIT
		Without load	f <sub>O</sub> = 170 MHz	65	80	
		Without load	f <sub>O</sub> = 200 MHz	75	90	
	Dunamia aurrent an V	Differential outputs terminated	f <sub>O</sub> = 170 MHz	110	140	A
I <sub>DD</sub> Dynamic current on V <sub>DDQ</sub>	Dynamic current on V <sub>DDQ</sub>	with 120 $\Omega$ , $C_L = 0$ pF	f <sub>O</sub> = 200 MHz	120	150	mA
		Differential outputs terminated   f <sub>O</sub> = 170 MHz	130	160		
		with 120 $\Omega$ , $C_L = 14 \text{ pF}$	f <sub>O</sub> = 200 MHz	140	170	
ΔC	Part-to-part input capacitance variation	$V_{DDQ} = 2.5 \text{ V}, V_{I} = V_{DDQ} \text{ or GNE}$	)		1	pF
$C_{I(\Delta)}$	Input capacitance difference between CLK and CLK, FBIN and FBIN	$V_{DDQ} = 2.5 \text{ V}, V_{I} = V_{DDQ} \text{ or GNE}$	)		0.25	pF

## **TIMING REQUIREMENTS**

over recommended ranges of supply voltage and operating free-air temperature

	PARAMETER	MIN	MAX	UNIT
t .	Operating clock frequency	60	220	MHz
† <sub>CLK</sub>	Application clock frequency	90	220	IVITIZ
	Input clock duty cycle	40%	60%	
	Stabilization time (PLL mode) <sup>(1)</sup>		10	μs
	Stabilization time (bypass mode) (2)		30	ns

<sup>(1)</sup> The time required for the integrated PLL circuit to obtain phase lock of its feedback signal to its reference signal. For phase lock to be obtained, a fixed-frequency, fixed-phase reference signal must be present at CLK and V<sub>DD</sub> must be applied. Until phase lock is obtained, the specifications for propagation delay, skew, and jitter parameters given in the switching characteristics table are not applicable. This parameter does not apply for input modulation under SSC application.

<sup>(2)</sup> A recovery time is required when the device goes from power-down mode into bypass mode (AV<sub>DD</sub> at GND).



## **SWITCHING CHARACTERISTICS**

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>PLH</sub> <sup>(1)</sup>	Low- to high-level propagation delay time	Test mode/CLK to any output		3.5		ns
t <sub>PHL</sub> <sup>(1)</sup>	High- to low-level propagation delay time	Test mode/CLK to any output		3.5		ns
t <sub>jit(per)</sub> (2)	Jitter (period), see Figure 7	100/133/167 MHz (PC1600/2100/2700)	-65		65	ps
Jit(por)	, , ,	200 MHz (PC3200)	-30		30	·
t <sub>jit(cc)</sub> (2)	Jitter (cycle-to-cycle), see Figure 4	100/133/167 MHz (PC1600/2100/2700)	-60		60	ps
jii(00)		200 MHz (PC3200)	-40		40	·
t <sub>jit(hper)</sub> (2)	Half-period jitter, see Figure 8	100/133/167 MHz (PC1600/2100/2700)	-100		100	ps
j.t(i.po.)		200 MHz (PC3200)	-75		75	
t <sub>slr(o)</sub>	Output clock slew rate, see Figure 9	Load: 120 Ω, 14 pF	1		2	V/ns
t <sub>(\phi)</sub>	Static phase offset, see Figure 5	100/133/167/200 MHz	-50		50	ps
t <sub>sk(o)</sub>	Output skew, see Figure 6	Load: 120 Ω, 14 pF; 100/133/167/200 MHz			40	ps

- (1) Refers to the transition of the noninverting output.(2) This parameter is assured by design but cannot be 100% production tested.

## PARAMETER MEASUREMENT INFORMATION

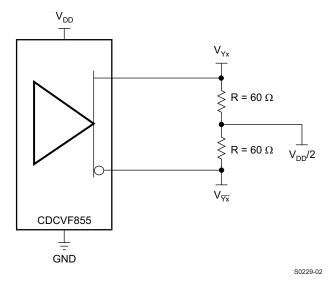


Figure 1. IBIS Model Output Load



## PARAMETER MEASUREMENT INFORMATION (continued)

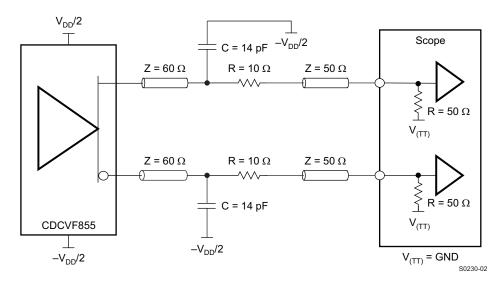


Figure 2. Output Load Test Circuit

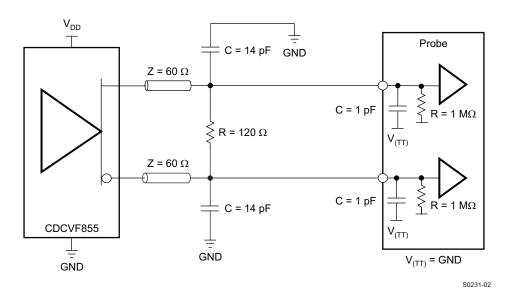


Figure 3. Output Load Test Circuit for Crossing Point

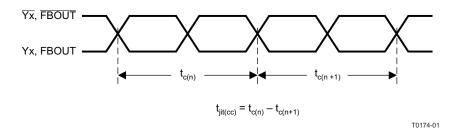


Figure 4. Cycle-to-Cycle Jitter



## PARAMETER MEASUREMENT INFORMATION (continued)

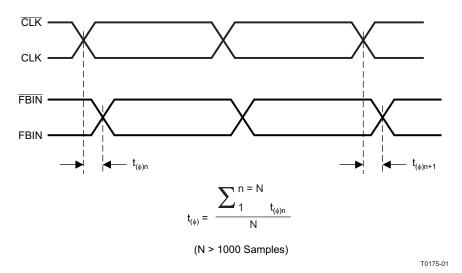


Figure 5. Phase Offset

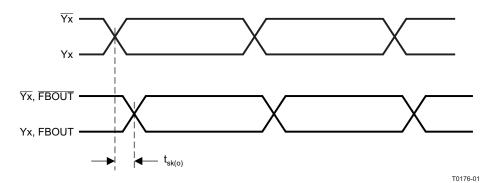


Figure 6. Output Skew

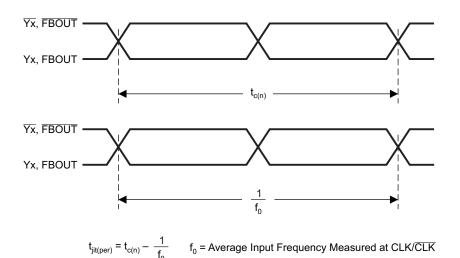


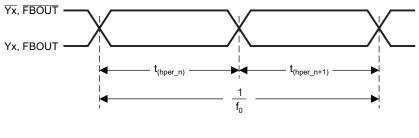
Figure 7. Period Jitter

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T0178-01



## PARAMETER MEASUREMENT INFORMATION (continued)



 $t_{jit(hper)} = t_{(hper\_n)} - \frac{1}{2 \times f_0} \hspace{1cm} \text{n = Any Half Cycle} \\ f_0 = \text{Average Input Frequency Measured at CLK/CLK}$ 

Figure 8. Half-Period Jitter

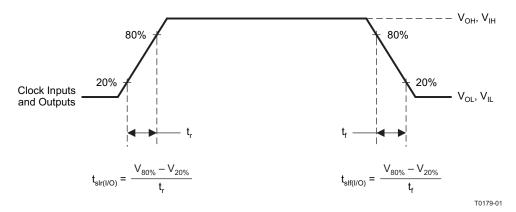
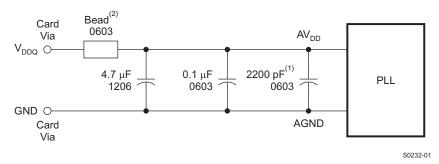


Figure 9. Input and Output Slew Rates



- (1) Place the 2200-pF capacitor close to the PLL.
- (2) Recommended bead: Fair-Rite P/N 2506036017Y0 or equilvalent (0.8  $\Omega$  dc maximum, 600  $\Omega$  at 100 MHz).

NOTE: Use a wide trace for the PLL analog power and ground. Connect PLL and capacitors to AGND trace and connect trace to one GND via (farthest from the PLL).

Figure 10. Recommended AV<sub>DD</sub> Filtering

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
CDCVF855PW	Active	Production	TSSOP (PW)   28	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CDCVF855
CDCVF855PW.A	Active	Production	TSSOP (PW)   28	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CDCVF855
CDCVF855PWG4	Active	Production	TSSOP (PW)   28	50   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CDCVF855
CDCVF855PWR	Active	Production	TSSOP (PW)   28	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CDCVF855
CDCVF855PWR.A	Active	Production	TSSOP (PW)   28	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CDCVF855

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

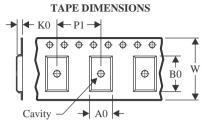
<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

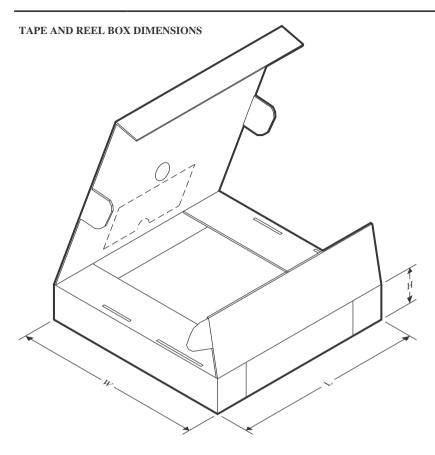


#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDCVF855PWR	TSSOP	PW	28	2000	330.0	16.4	6.75	10.1	1.8	12.0	16.0	Q1

# **PACKAGE MATERIALS INFORMATION**

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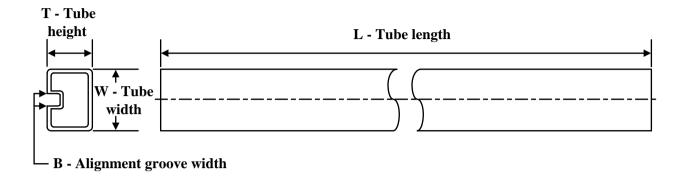
## \*All dimensions are nominal

	Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	CDCVF855PWR	TSSOP	PW	28	2000	353.0	353.0	32.0	

# **PACKAGE MATERIALS INFORMATION**

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## **TUBE**

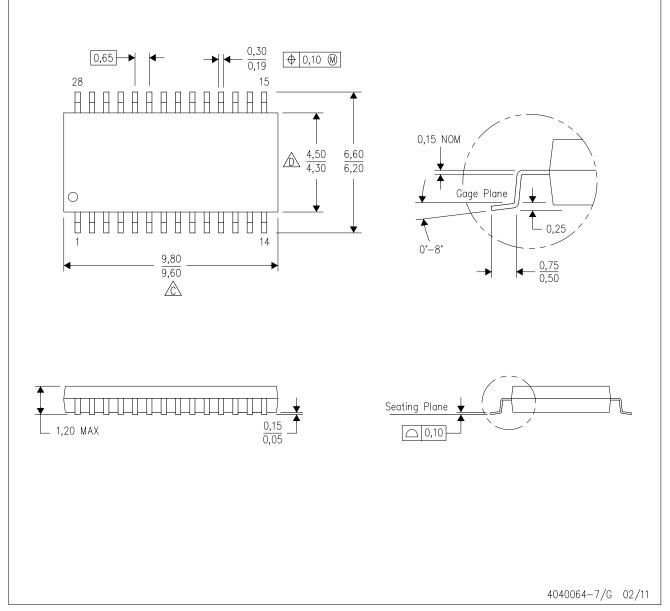


## \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CDCVF855PW	PW	TSSOP	28	50	530	10.2	3600	3.5
CDCVF855PW.A	PW	TSSOP	28	50	530	10.2	3600	3.5
CDCVF855PWG4	PW	TSSOP	28	50	530	10.2	3600	3.5

PW (R-PDSO-G28)

## PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



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